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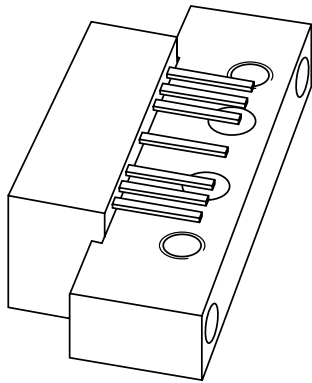
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# DATA SHEET



## **BGD904L**

**860 MHz, 20 dB gain power  
doubler amplifier**

Product specification  
Supersedes data of 1999 Aug 17

2001 Nov 01

# 860 MHz, 20 dB gain power doubler amplifier

# BGD904L

### FEATURES

- Excellent linearity
- Extremely low noise
- Excellent return loss properties
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability
- Low DC current consumption.

### APPLICATIONS

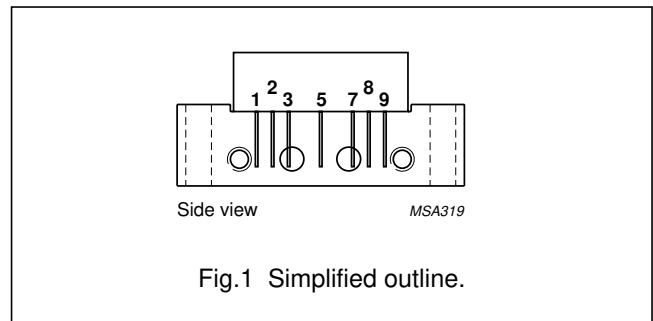
- CATV systems operating in the 40 to 900 MHz frequency range.

### DESCRIPTION

Hybrid amplifier module in a SOT115J package operating with a supply voltage of 24 V.

### PINNING - SOT115J

| PIN | DESCRIPTION     |
|-----|-----------------|
| 1   | input           |
| 2   | common          |
| 3   | common          |
| 5   | +V <sub>B</sub> |
| 7   | common          |
| 8   | common          |
| 9   | output          |



### QUICK REFERENCE DATA

| SYMBOL           | PARAMETER                      | CONDITIONS            | MIN. | MAX. | UNIT |
|------------------|--------------------------------|-----------------------|------|------|------|
| G <sub>p</sub>   | power gain                     | f = 50 MHz            | 19.7 | 20.3 | dB   |
|                  |                                | f = 900 MHz           | 20.5 | 21.5 | dB   |
| I <sub>tot</sub> | total current consumption (DC) | V <sub>B</sub> = 24 V | 350  | 380  | mA   |

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL           | PARAMETER                           | MIN. | MAX. | UNIT |
|------------------|-------------------------------------|------|------|------|
| V <sub>B</sub>   | supply voltage                      | –    | 30   | V    |
| V <sub>i</sub>   | RF input voltage                    | –    | 70   | dBmV |
| T <sub>stg</sub> | storage temperature                 | –40  | +100 | °C   |
| T <sub>mb</sub>  | operating mounting base temperature | –20  | +100 | °C   |

## 860 MHz, 20 dB gain power doubler amplifier

BGD904L

**CHARACTERISTICS**Bandwidth 40 to 900 MHz;  $V_B = 24$  V;  $T_{mb} = 35$  °C;  $Z_S = Z_L = 75$   $\Omega$ .

| SYMBOL           | PARAMETER              | CONDITIONS  | MIN. | TYP.  | MAX.  | UNIT |
|------------------|------------------------|---|------|-------|-------|------|
| G <sub>p</sub>   | power gain             | f = 50 MHz  | 19.7 | 20    | 20.3  | dB   |
|                  |                        | f = 900 MHz   | 20.5 | 21    | 21.5  | dB   |
| SL               | slope straight line    | f = 40 to 900 MHz   | 0.4  | 0.9   | 1.4   | dB   |
| FL               | flatness straight line | f = 40 to 900 MHz   | –    | ±0.15 | ±0.3  | dB   |
| S <sub>11</sub>  | input return losses    | f = 40 to 80 MHz  | 21   | 25    | –     | dB   |
|                  |                        | f = 80 to 160 MHz   | 22   | 30    | –     | dB   |
|                  |                        | f = 160 to 320 MHz  | 21   | 29    | –     | dB   |
|                  |                        | f = 320 to 550 MHz  | 18   | 24    | –     | dB   |
|                  |                        | f = 550 to 650 MHz  | 17   | 22    | –     | dB   |
|                  |                        | f = 650 to 900 MHz  | 16   | 21    | –     | dB   |
| S <sub>22</sub>  | output return losses   | f = 40 to 80 MHz  | 25   | 29    | –     | dB   |
|                  |                        | f = 80 to 160 MHz   | 23   | 28    | –     | dB   |
|                  |                        | f = 160 to 320 MHz  | 19   | 25    | –     | dB   |
|                  |                        | f = 320 to 750 MHz  | 18   | 24    | –     | dB   |
|                  |                        | f = 750 to 900 MHz  | 17   | 23    | –     | dB   |
| S <sub>21</sub>  | phase response         | f = 50 MHz  | –45  | –     | +45   | deg  |
| CTB              | composite triple beat  | 49 channels flat; V <sub>o</sub> = 47 dBmV;<br>f <sub>m</sub> = 859.25 MHz                  | –    | –65.5 | –64   | dB   |
|                  |                        | 77 channels flat; V <sub>o</sub> = 44 dBmV;<br>f <sub>m</sub> = 547.25 MHz                  | –    | –67.5 | –65.5 | dB   |
|                  |                        | 110 channels flat; V <sub>o</sub> = 44 dBmV;<br>f <sub>m</sub> = 745.25 MHz                 | –    | –61   | –59.5 | dB   |
|                  |                        | 129 channels flat; V <sub>o</sub> = 44 dBmV;<br>f <sub>m</sub> = 859.25 MHz                 | –    | –57   | –55   | dB   |
|                  |                        | 110 channels; f <sub>m</sub> = 397.25 MHz;<br>V <sub>o</sub> = 49 dBmV at 550 MHz; note 1   | –    | –61.5 | –59.5 | dB   |
|                  |                        | 129 channels; f <sub>m</sub> = 649.25 MHz;<br>V <sub>o</sub> = 49.5 dBmV at 860 MHz; note 2 | –    | –56   | –54   | dB   |
| X <sub>mod</sub> | cross modulation       | 49 channels flat; V <sub>o</sub> = 47 dBmV;<br>f <sub>m</sub> = 55.25 MHz                   | –    | –64   | –61   | dB   |
|                  |                        | 77 channels flat; V <sub>o</sub> = 44 dBmV;<br>f <sub>m</sub> = 55.25 MHz                   | –    | –66.5 | –64   | dB   |
|                  |                        | 110 channels flat; V <sub>o</sub> = 44 dBmV;<br>f <sub>m</sub> = 55.25 MHz                  | –    | –63   | –60.5 | dB   |
|                  |                        | 129 channels flat; V <sub>o</sub> = 44 dBmV;<br>f <sub>m</sub> = 55.25 MHz                  | –    | –61.5 | –59   | dB   |
|                  |                        | 110 channels; f <sub>m</sub> = 397.25 MHz;<br>V <sub>o</sub> = 49 dBmV at 550 MHz; note 1   | –    | –60   | –57.5 | dB   |
|                  |                        | 129 channels; f <sub>m</sub> = 859.25 MHz;<br>V <sub>o</sub> = 49.5 dBmV at 860 MHz; note 2 | –    | –56   | –53.5 | dB   |

## 860 MHz, 20 dB gain power doubler amplifier

## BGD904L

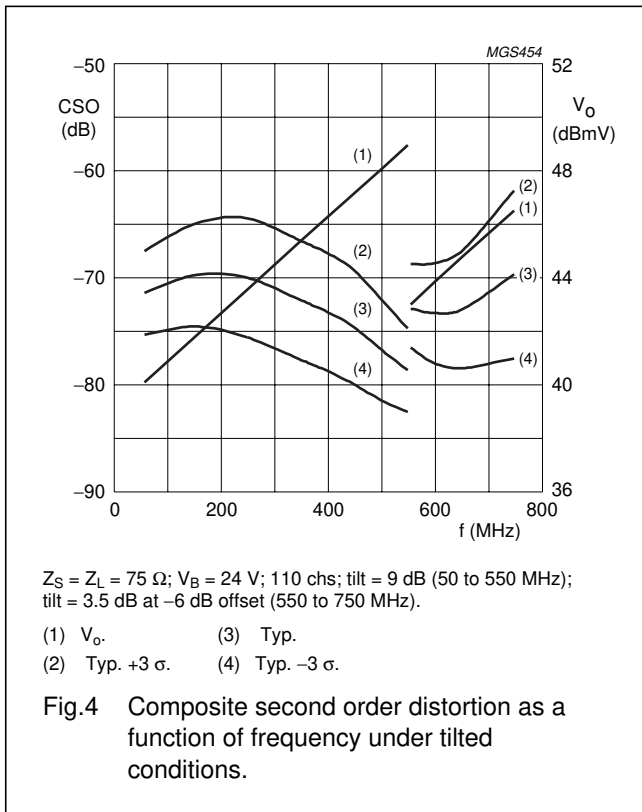
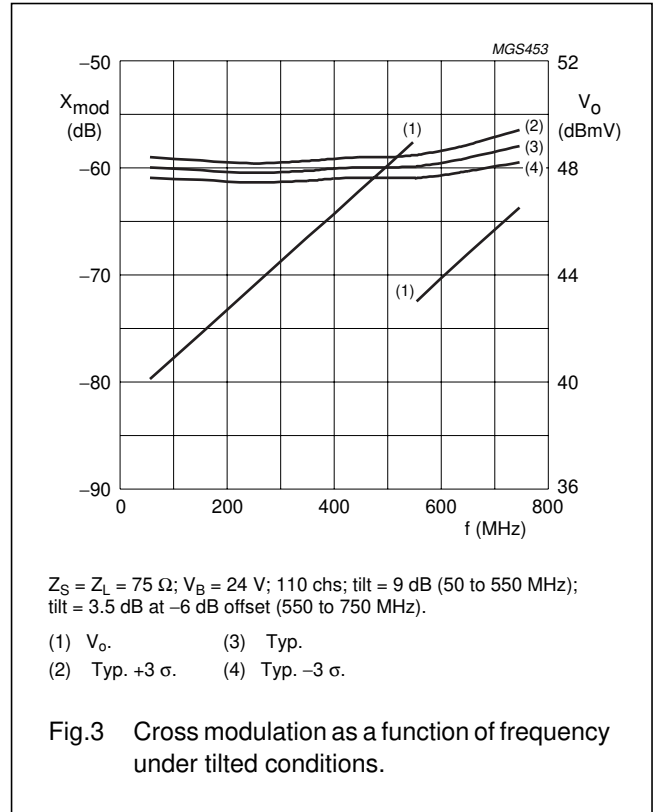
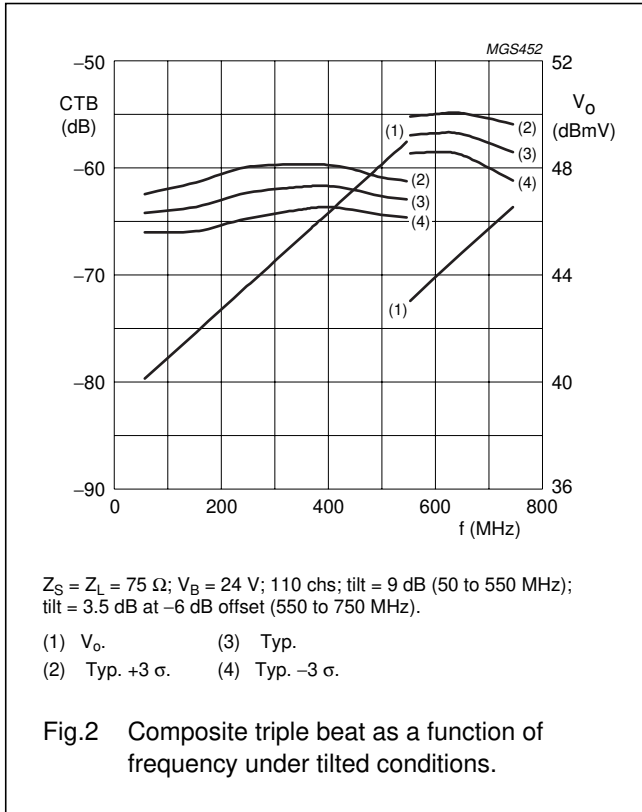
| SYMBOL    | PARAMETER                         | CONDITIONS   | MIN. | TYP. | MAX. | UNIT |
|-----------|-----------------------------------|--|------|------|------|------|
| CSO       | composite second order distortion | 49 channels flat; $V_o = 47$ dBmV;<br>$f_m = 860.5$ MHz                | –    | –69  | –63  | dB   |
|           |                                   | 77 channels flat; $V_o = 44$ dBmV;<br>$f_m = 548.5$ MHz                | –    | –73  | –68  | dB   |
|           |                                   | 110 channels flat; $V_o = 44$ dBmV;<br>$f_m = 746.5$ MHz               | –    | –69  | –63  | dB   |
|           |                                   | 129 channels flat; $V_o = 44$ dBmV;<br>$f_m = 860.5$ MHz               | –    | –65  | –59  | dB   |
|           |                                   | 110 channels; $f_m = 150$ MHz;<br>$V_o = 49$ dBmV at 550 MHz; note 1   | –    | –68  | –63  | dB   |
|           |                                   | 129 channels; $f_m = 150$ MHz;<br>$V_o = 49.5$ dBmV at 860 MHz; note 2 | –    | –63  | –58  | dB   |
| $d_2$     | second order distortion           | note 3   | –    | –82  | –75  | dB   |
|           |                                   | note 4   | –    | –83  | –76  | dB   |
|           |                                   | note 5   | –    | –83  | –77  | dB   |
| $V_o$     | output voltage                    | $d_{im} = -60$ dB; note 6  | 62.5 | 64   | –    | dBmV |
|           |                                   | $d_{im} = -60$ dB; note 7  | 63.5 | 65.5 | –    | dBmV |
|           |                                   | $d_{im} = -60$ dB; note 8  | 65.5 | 67.5 | –    | dBmV |
|           |                                   | CTB compression = 1 dB;<br>129 channels flat; $f = 859.25$ MHz         | 47.5 | 48.5 | –    | dBmV |
|           |                                   | CSO compression = 1 dB;<br>129 channels flat; $f = 860.5$ MHz          | 50   | 52   | –    | dBmV |
| NF        | noise figure                      | $f = 50$ MHz   | –    | 3.8  | 5    | dB   |
|           |                                   | $f = 550$ MHz  | –    | 4.1  | 5.5  | dB   |
|           |                                   | $f = 750$ MHz  | –    | 4.8  | 6.5  | dB   |
|           |                                   | $f = 900$ MHz  | –    | 5.9  | 7.5  | dB   |
| $I_{tot}$ | total current consumption (DC)    | note 9   | 350  | 365  | 380  | mA   |

**Notes**

- Tilt = 9 dB (50 to 550 MHz); tilt = 3.5 dB at –6 dB offset (550 to 750 MHz).
- Tilt = 12.5 dB (50 to 860 MHz).
- $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 805.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 860.5$  MHz.
- $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 691.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 746.5$  MHz.
- $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- Measured according to DIN45004B:  
 $f_p = 851.25$  MHz;  $V_p = V_o$ ;  $f_q = 858.25$  MHz;  $V_q = V_o - 6$  dB;  
 $f_r = 860.25$  MHz;  $V_r = V_o - 6$  dB; measured at  $f_p + f_q - f_r = 849.25$  MHz.
- Measured according to DIN45004B:  
 $f_p = 740.25$  MHz;  $V_p = V_o$ ;  $f_q = 747.25$  MHz;  $V_q = V_o - 6$  dB;  $f_r = 749.25$  MHz;  $V_r = V_o - 6$  dB;  
measured at  $f_p + f_q - f_r = 738.25$  MHz.
- Measured according to DIN45004B:  
 $f_p = 540.25$  MHz;  $V_p = V_o$ ;  $f_q = 547.25$  MHz;  $V_q = V_o - 6$  dB;  $f_r = 549.25$  MHz;  $V_r = V_o - 6$  dB;  
measured at  $f_p + f_q - f_r = 538.25$  MHz.
- The module normally operates at  $V_B = 24$  V, but is able to withstand supply transients up to 35 V.

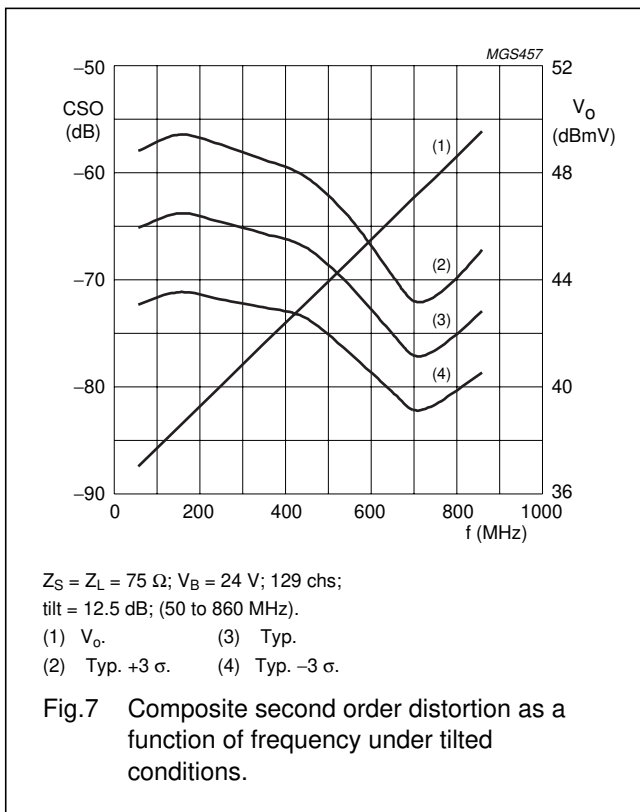
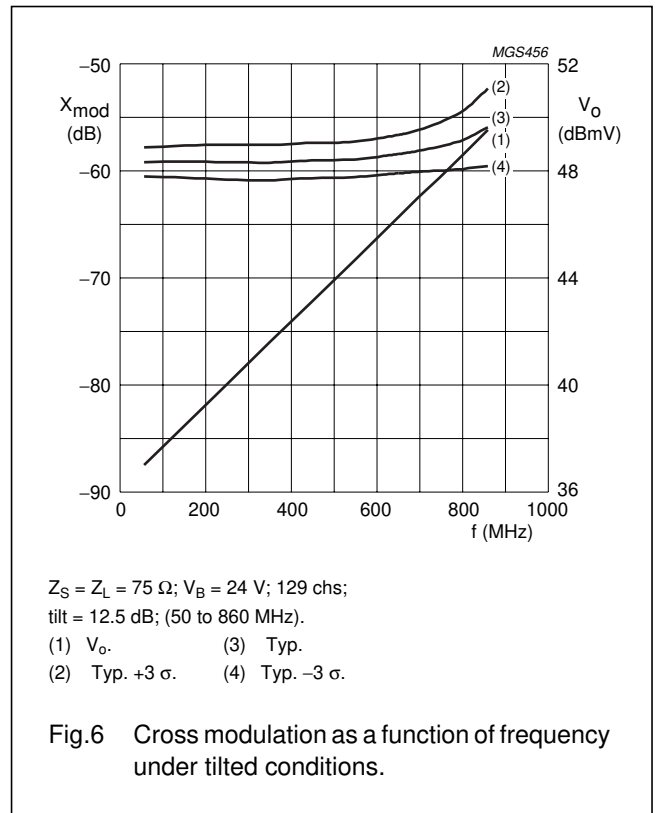
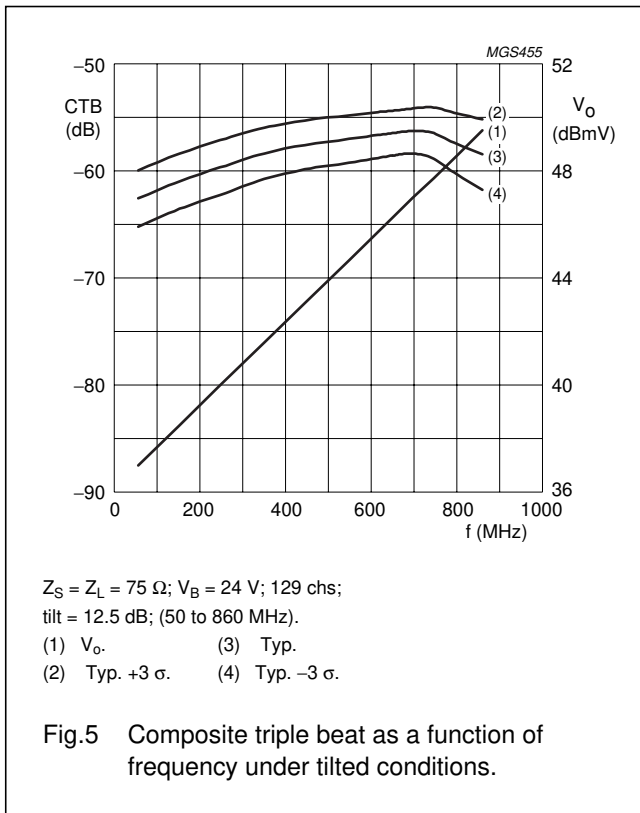
860 MHz, 20 dB gain power doubler amplifier

BGD904L



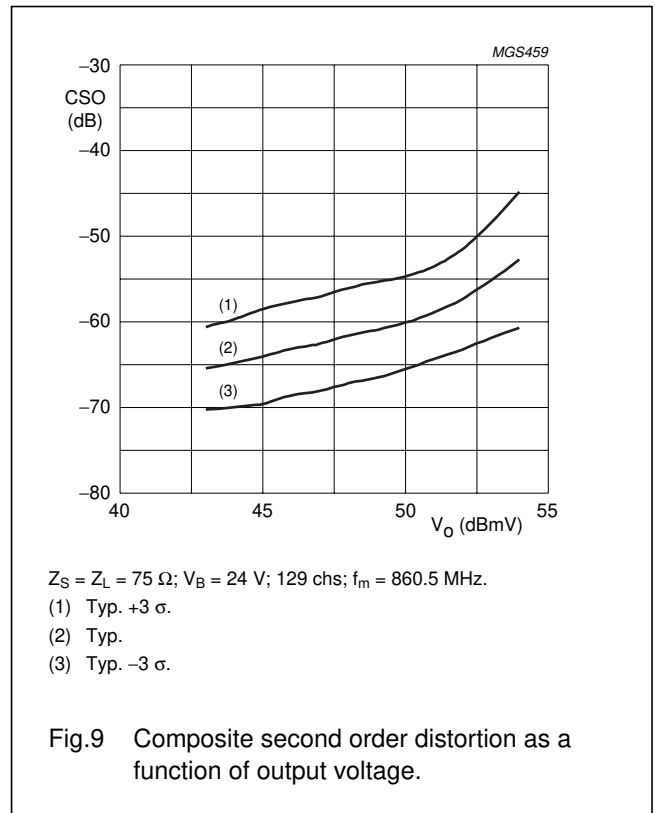
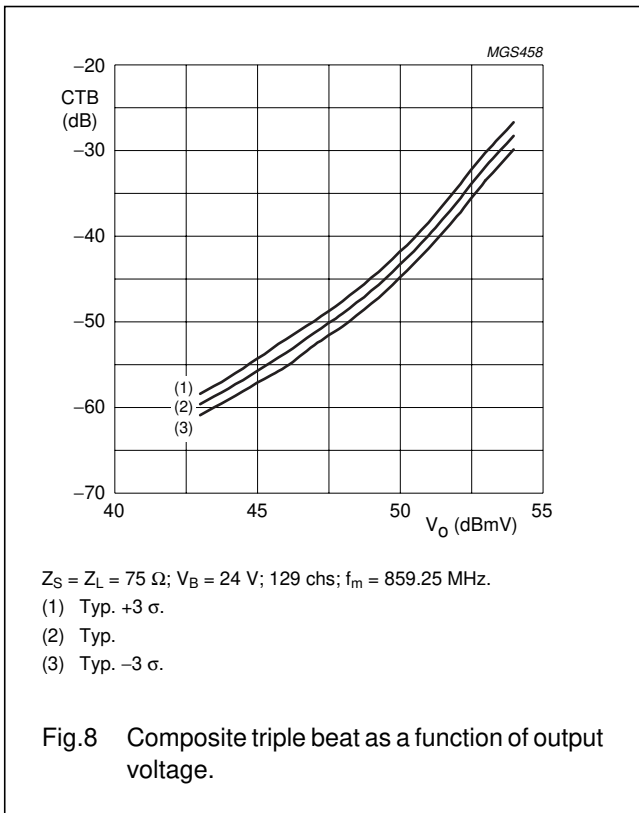
860 MHz, 20 dB gain power doubler amplifier

BGD904L



860 MHz, 20 dB gain power doubler amplifier

BGD904L





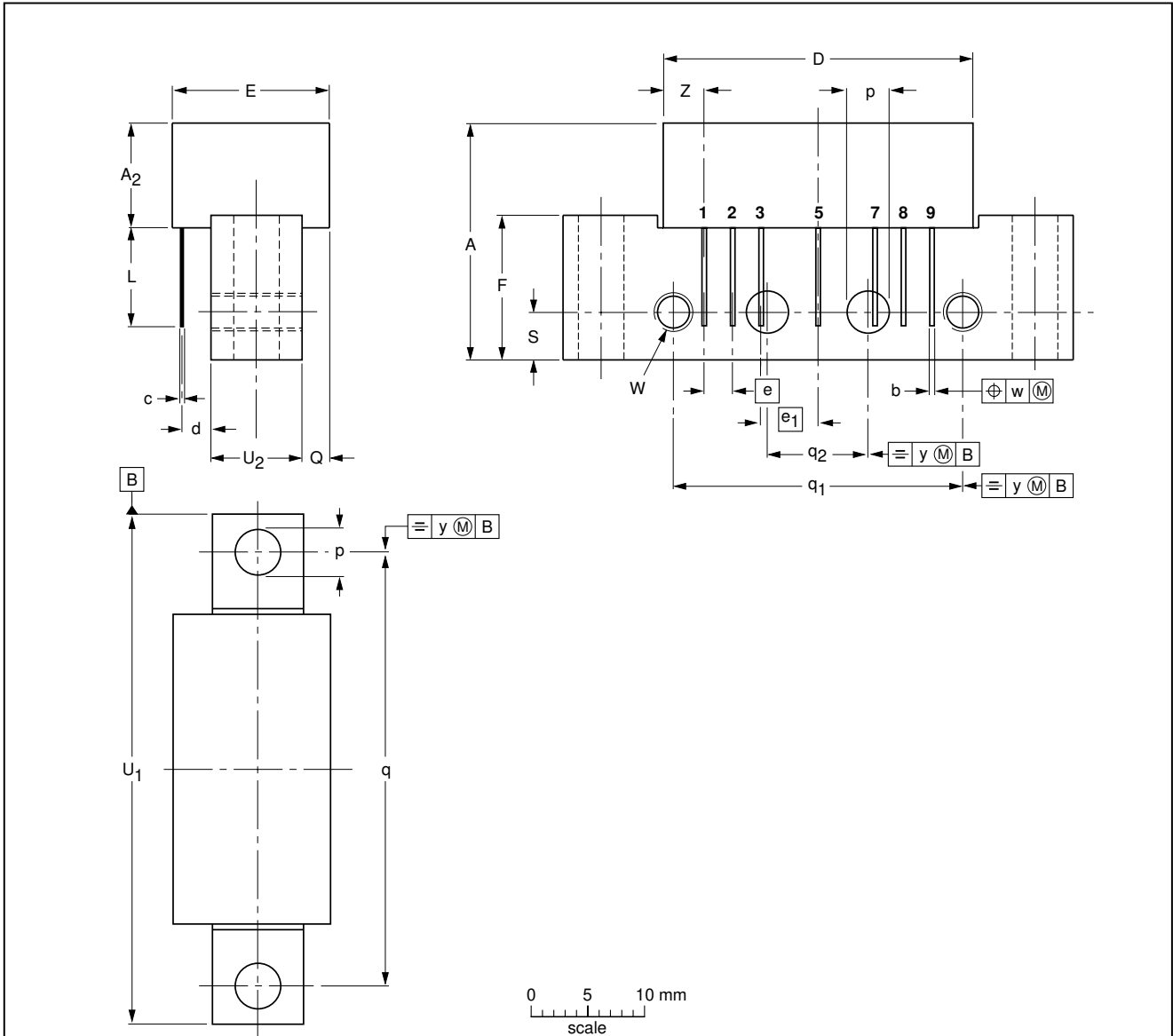
860 MHz, 20 dB gain power doubler amplifier

BGD904L

PACKAGE OUTLINE

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



DIMENSIONS (mm are the original dimensions)

| UNIT | A max. | A <sub>2</sub> max. | b            | c    | D max. | d max. | E max. | e    | e <sub>1</sub> | F    | L min. | p            | Q max. | q    | q <sub>1</sub> | q <sub>2</sub> | S   | U <sub>1</sub> max. | U <sub>2</sub> | W           | w    | y   | Z max. |
|------|--------|---------------------|--------------|------|--------|--------|--------|------|----------------|------|--------|--------------|--------|------|----------------|----------------|-----|---------------------|----------------|-------------|------|-----|--------|
| mm   | 20.8   | 9.1                 | 0.51<br>0.38 | 0.25 | 27.2   | 2.54   | 13.75  | 2.54 | 5.08           | 12.7 | 8.8    | 4.15<br>3.85 | 2.4    | 38.1 | 25.4           | 10.2           | 4.2 | 44.75               | 8              | 6-32<br>UNC | 0.25 | 0.1 | 3.8    |

| OUTLINE VERSION | REFERENCES |       |      |  | EUROPEAN PROJECTION | ISSUE DATE |
|-----------------|------------|-------|------|--|---------------------|------------|
|                 | IEC        | JEDEC | EIAJ |  |                     |            |
| SOT115J         |            |       |      |  |                     | 99-02-06   |

## 860 MHz, 20 dB gain power doubler amplifier

BGD904L

## DATA SHEET STATUS

| DATA SHEET STATUS <sup>(1)</sup> | PRODUCT STATUS <sup>(2)</sup> | DEFINITIONS  |
|----------------------------------|-------------------------------|--|
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**NOTES**

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**NOTES**

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